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Modulation spectroscopy study of a strained layer GaAs/GaAsP multiple quantum well structure

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Interface effects of strained semiconductor heterostructure in longitudinal magnetic field

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Photodetector with controlled photosensitivity in 1.1-1.6 μm spectral range

Snigur Anatolii, Brînzari Vladimir, Dorogan Valerian, Korotcenkov Ghenadie, Savastru Roxana

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Andronic Ion, Simașchevici Alexei, Potlog Tamara, Șerban Dormidont, Chetruș Petru

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